

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	121	257/351.cor.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 11:10
L9	237	257/350.cor.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 10:50
L8	83	257/349.cor.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 10:11
L3	100	257/211.cor.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 10:05
L7	2	"6426558".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 09:58
L6	336	257/347.cor. and (thin near film near transistor or tft)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 09:58
L2	34	(gate) near5 (sidewall or side) near2 (spacer) near5 (optional or absent)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 09:23
L1	27	(gate) near5 (sidewall) near5 (spacer) near5 (omit or omitted or omission or omitting)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 08:56
S1	70338	(soi or box or buried near oxide) and (interconnect or interconnection or lic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 08:51
S57	390	soi with sram	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 13:12
S34	344	soi with sram	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 13:12
S56	248	(soi or silicon adj on adj insulator) near6 (sram or sdram or dsram)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 12:47

S55	191	(soi or box or buried near oxide or tft) and (wiring or interconnection or interconnect or lic) near3 gate near4 (source or drain or impurity or doped or active) and (sram or sdram or dsram)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 12:42
S19	221	(soi or silicon adj on adj insulator) near6 (sram or sdram or dsram)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 12:42
S17	162	(soi or box or buried near oxide or tft) and (wiring or interconnection or interconnect or lic) near3 gate near4 (source or drain or impurity or doped or active) and (sram or sdram or dsram)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 10:40
S54	114	(tft) and (lic or local near interconnect or local near inter near connect or local near inter-connect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 10:29
S7	97	(tft) and (lic or local near interconnect or local near inter near connect or local near inter-connect)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 10:29
S53	338	(soi or box or buried near oxide) and (lic or local near interconnect or local near inter near connect or local near inter-connect) and gate and (source or drain or active) and sram	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 10:08
S6	298	(soi or box or buried near oxide) and (lic or local near interconnect or local near inter near connect or local near inter-connect) and gate and (source or drain or active) and sram	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/28 10:08